

UTC UNISONIC TECHNOLOGIES CO., LTD

7N80Z

Power MOSFET

7A, 800V N-CHANNEL **POWER MOSFET**

DESCRIPTION

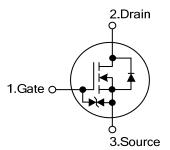
The UTC 7N80Z is an N-channel mode power MOSFET using UTC's advanced technology to provide customers with planar stripe and DMOS technology. This technology specializes in allowing a minimum on-state resistance and superior switching performance. It also can withstand high energy pulse in the avalanche and commutation mode.

The UTC 7N80Z is universally applied in high efficiency switch mode power supply.

FEATURES

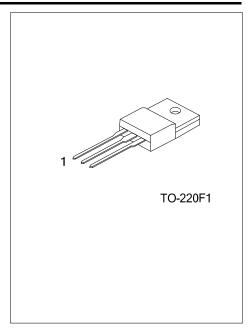
- * R_{DS(on)}=1.8Ω@V_{GS} =10V
- * High switching speed
- * 100% avalanche tested

SYMBOL



ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Deaking		
Lead Free	Lead Free Halogen Free		1	2	3	Packing		
7N80ZL-TF1-T	7N80ZG-TF1-T	TO-220F1	G	D	S	Tube		
Note: Pin Assignment: G: Gate D: Drain S: Source								
7N80ZL-TF1-T (1)Packing Type (2)Package Type (3)Lead Free		 (1) T: Tube (2) TF1: TO-220F1 (3) L: Lead Free, G: Halogen Free 						



■ ABSOLUTE MAXIMUM RATINGS (T_c=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V _{DSS}	800	V
Gate-Source Voltage		V _{GSS}	±20	V
Drain Current	Continuous	I _D	7	А
	Pulsed (Note 1)	I _{DM}	26.4	А
Avalanche Energy	Single Pulsed (Note 2)	E _{AS}	580	mJ
	Repetitive (Note 1)	E _{AR}	16.7	mJ
Peak Diode Recovery dv/dt (Note 3)		dv/dt	4.5	V/ns
Power Dissipation		PD	52	W
Junction Temperature		ТJ	+150	°C
Storage Temperature		T _{STG}	-55~+150	°C

Note: 1. Repetitive Rating: Pulse width limited by maximum junction temperature

2. L=25mH, I_{AS} =6.6A, V_{DD} = 50V, R_G =25 Ω , Starting T_J =25°C

3. I_{SD} ≤8A, di/dt ≤200A/µs, V_{DD} ≤BV_{DSS}, Starting T_J=25°C

4. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	θ _{JA}	62.5	°C/W	
Junction to Case	θις	2.4	°C/W	



■ ELECTRICAL CHARACTERISTICS (T_C=25°C, unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage		BV _{DSS}	V _{GS} =0V, I _D =250µA	800			V
Breakdown Voltage Temperature Coefficient		$\Delta BV_{DSS}/\Delta T_{J}$	I _D =250µA,Referenced to 25°C		0.93		V/°C
Drain-Source Leakage Current		I _{DSS}	V _{DS} =800V, V _{GS} =0V			10	μA
			V _{DS} =640V, T _C =125°C			100	μA
Gate-Source Leakage Current	Forward		V _{DS} =0V ,V _{GS} =20V			5	μA
	Reverse	I _{GSS}	V _{DS} =0V ,V _{GS} =-20V			-5	μA
ON CHARACTERISTICS							
Gate Threshold Voltage		V _{GS(TH)}	V _{DS} =V _{GS} , I _D =250µA 3			5.0	V
Drain-Source On-State Resistance		R _{DS(ON)}	V _{GS} =10V, I _D =3.3A		1.4	1.8	Ω
DYNAMIC PARAMETERS					_		
Input Capacitance		CISS			1290	1680	рF
Output Capacitance		C _{OSS}	V _{DS} =25V,V _{GS} =0V,f=1.0MHz		120	155	рF
Reverse Transfer Capacitance		C _{RSS}			10	13	рF
SWITCHING PARAMETERS					_		
Total Gate Charge		Q_{G}			27	35	nC
Gate-Source Charge		Q _{GS}	V _{DS} =640V, V _{GS} =10V, I _D =6.6A (Note 1,2)		8.2		nC
Gate-Drain Charge		Q _{GD}			11		nC
Turn-ON Delay Time		t _{D(ON)}			35	80	ns
Turn-ON Rise Time		t _R	V _{DD} =400V, I _D =6.6A, R _G =25Ω		100	210	ns
Turn-OFF Delay Time		t _{D(OFF)}	(Note 1,2)		50	110	ns
Turn-OFF Fall Time		t _F			60	130	ns
SOURCE- DRAIN DIODE RATIN	NGS AND CI	HARACTERI	STICS				
Maximum Body-Diode Continuous Current		Is				6.6	Α
Maximum Body-Diode Pulsed Current		I _{SM}				26.4	Α
Drain-Source Diode Forward Voltage		V _{SD}	I _S =6.6A, V _{GS} =0V			1.4	V
Body Diode Reverse Recovery Time		t _{rr}	V _{GS} =0V, I _S =6.6A,		650		ns
Body Diode Reverse Recovery Charge		Q _{RR}	dl _F /dt=100A/µs (Note 1)		7.0		μC

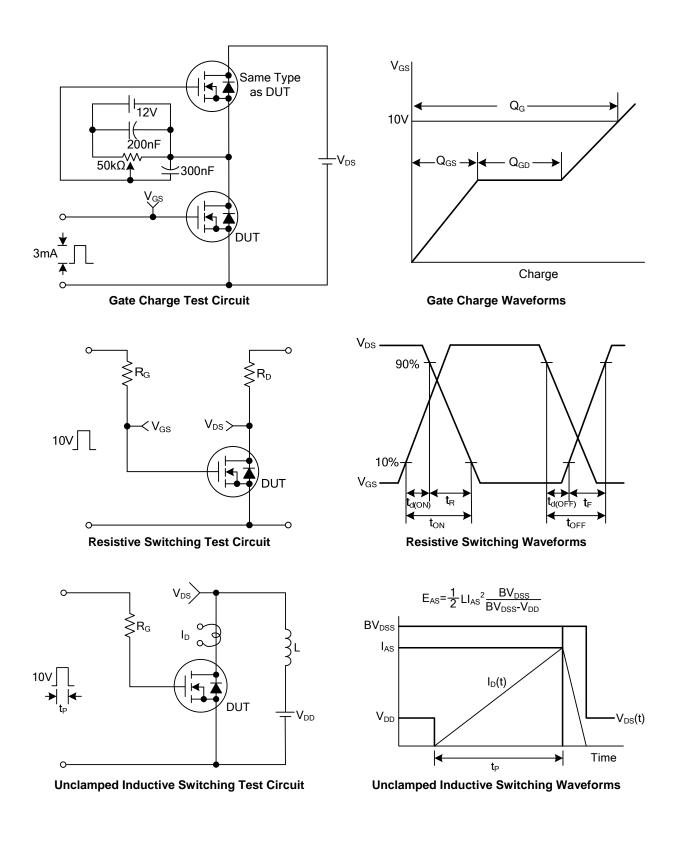
Note: 1. Pulse Test: Pulse width \leq 300µs, Duty cycle \leq 2%

2. Essentially independent of operating temperature



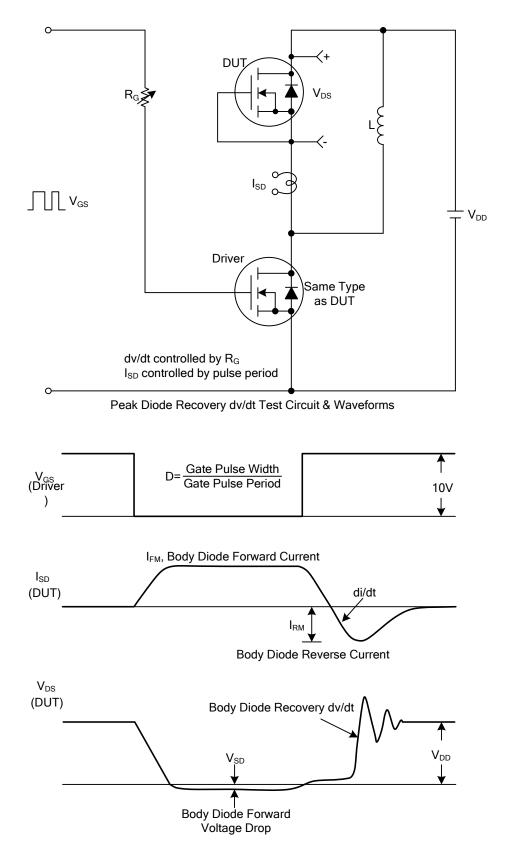
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TEST CIRCUITS AND WAVEFORMS





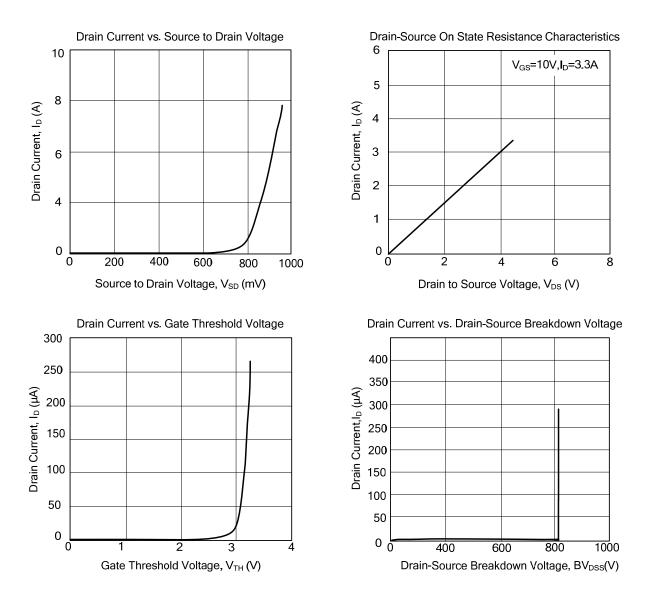
■ TEST CIRCUITS AND WAVEFORMS(Cont.)





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TYPICAL CHARACTERISTICS



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